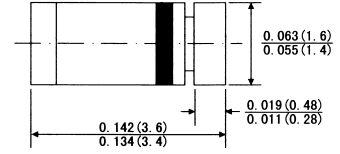


FEATURES

. In MiniMELF case especially for automated insertion
 The zener voltage are graded according to the international E24
 standard. Smaller voltage tolerances and higher zener voltage
 on request

Mini-MELF



Dimensions in inches and (millimeters)

MECHANICAL DATA

. **Case:** Mini-MELF(SOD-80) glass case
 . **weight:** Approx. 0.05 gram

ABSOLUTE MAXIMUM RATINGS(LIMITING VALUES)(TA=25°C)

	Symbols	Value	Units
Zener current see table "Characteristics"			
Power dissipation at TA=25°C	P _{tot}	500 ¹⁾	mW
Junction temperature	T _J	175	°C
Storage temperature range	T _{STG}	-55 to +175	°C
1)Valid provided that a distance of 8mm from case are kept at ambient temperature			

ELECTRICAL CHARACTERISTICS(TA=25°C)

	Symbols	Min	Typ	Max	Units
Thermal resistance junction to ambient	R _{θj-a}			300 ¹⁾	K/W
1) Valid provided that a distance at 8mm from case are kept at ambient temperature					

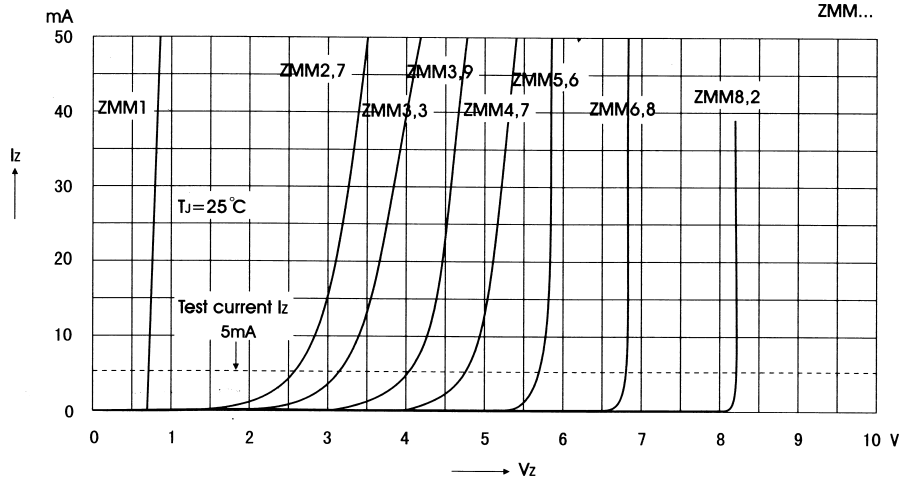
ZMM1 THRU ZMM200 SILICON PLANAR ZENER DIODES

Type	Zener Voltage range 1)			Dynamic resistance 1)			Maximum reverse Leakage Current			of zener voltage	
	V _{znom} 3)	I _{ZT}		r _{ZT} and r _{ZK} at I _{ZK}			I _R and I _R at V _R 2)			TK _{vz}	
	v	mA	V	Ω	Ω	mA	μ A	μ A	V	%/K	
ZMM1 ³⁾	0.75	5	0.7...0.8	<8	<50	1	--	--	--	-0.26...-0.23	
ZMM2.0	2.0		1.9...2.1	<85	<600		<100	<200	1	-0.09...-0.06	
ZMM2.4	2.4		2.28...2.56				<50	<100		-0.09...-0.06	
ZMM2.7	2.7		2.5...2.9				<10	<50		-0.09...-0.06	
ZMM3.0	3.0		2.8...3.2				<4	<40		-0.08...-0.05	
ZMM3.3	3.3		3.1...3.5				<2			-0.08...-0.05	
ZMM3.6	3.6		3.4...3.8				<2			-0.08...-0.05	
ZMM3.9	3.9		3.7...4.1				<2			-0.08...-0.05	
ZMM4.3	4.3		4.0...4.6				<75	<1		<20	-0.06...-0.03
ZMM4.7	4.7		4.4...5.0				<60	<0.5		<10	-0.05...+0.05
ZMM5.1	5.1		4.8...5.4				<35	<550		<2	2
ZMM5.6	5.6		5.2...6.0	<25	<450		3	0.03...0.07			
ZMM6.2	6.2		5.8...6.6	<10	<200		5	0.03...0.08			
ZMM6.8	6.8		6.4...7.2	<8	<150		6.2	0.03...0.09			
ZMM7.5	7.5		7.0...7.9	<7	<50		6.8	0.03...0.1			
ZMM8.2	8.2		7.7...8.7	<7			7.5	0.03...0.11			
ZMM9.1	9.1		8.5...9.6	<10	<0.1		8.2	0.03...0.11			
ZMM10	10		9.4...10.6	<15			<70	9.1	0.03...0.11		
ZMM11	11		10.4...11.6	<20			<70	10	0.03...0.11		
ZMM12	12		11.4...12.7	<20			<90	11	0.03...0.11		
ZMM13	13	12.4...14.1	<26	<110		12	0.03...0.11				
ZMM15	15	13.8...15.6	<30	<110		13	0.03...0.11				
ZMM16	16	15.3...17.1	<40	<170		15	0.03...0.11				
ZMM18	18	16.8...19.1	<50	<170		16	0.04...0.12				
ZMM20	20	18.8...21.2	<55	<220		18					
ZMM22	22	20.8...23.3	<55			20					
ZMM24	24	22.8...25.6	<80		22						
ZMM27	27	25.1...28.9			24						
ZMM30	30	28...32	<90		<500	27					
ZMM33	33	31...35			<110	<600		30			
ZMM36	36	34...38			<125	<700		33			
ZMM39	39	37...41			<135	<1000		36			
ZMM43	43	40...46			<150	0.25		39			
ZMM47	47	44...50			<200		43				
ZMM51	51	48...54		<250	47						
ZMM56	56	52...60		<300	<1500		51				
ZMM62	62	58...66		<450	<2000		56				
ZMM68	68	64...72		<600	<5000		62				
ZMM75	75	70...79	<800	<5500	68						
ZMM82	82	77...87	<950	<6000	75						
ZMM91	91	85...96	<1250	<6500	82						
ZMM100	100	94...106	<1400	<7000	91						
ZMM110	110	104...116	<1700	<8500	100						
ZMM120	120	114...127	<2000	<10000	110						
ZMM130	130	124...141	<2500	<12500	120						
ZMM150	150	138...156	<3000	<15000	130						
ZMM160	160	153...171	<3500	<17500	150						
ZMM180	180	168...191	<4000	<20000							
ZMM200	200	188...212	<4500	<22500							

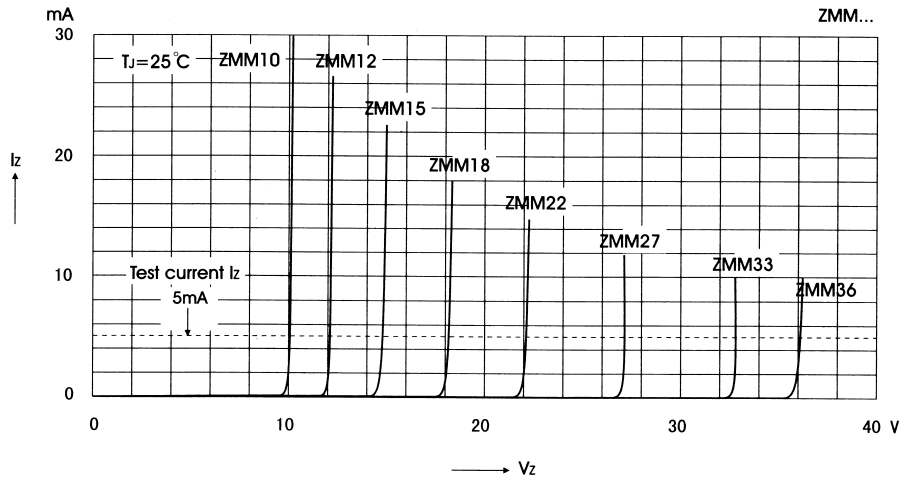
1) Tested with pulse tp=20ms
 2) Valid provided that electrodes are kept at ambient temperature
 3) The ZMM1 is a silicon diode with operation in forward direction. Hence, the index of all parameters should be "F" instead of "Z", Connect the cathode to the negative pole.

ZMM1...ZMM200 SILICON PLANER ZENER DIODES

BREAKDOWN CHARACTERISTICS AT T_J=CONSTANT (PULSED)

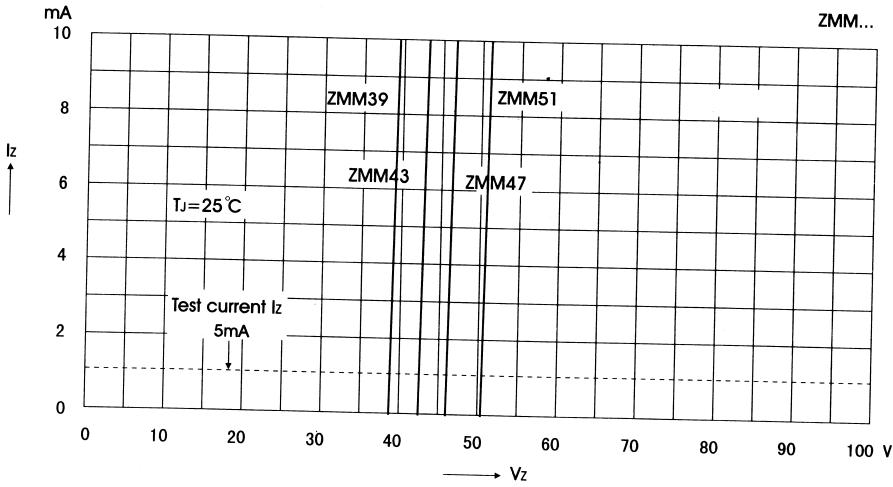


BREAKDOWN CHARACTERISTICS AT T_J=CONSTANT (PULSED)

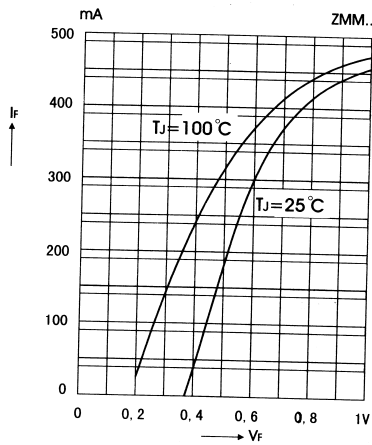


ZMM1...ZMM200 SILICON PLANER ZENER DIODES

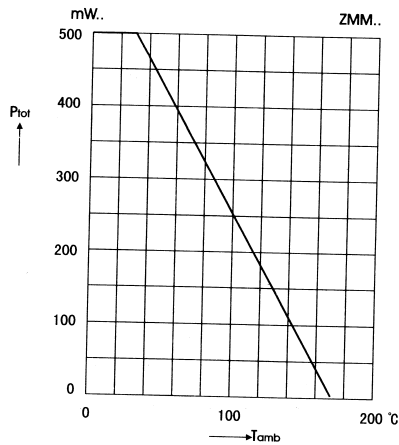
BREAKDOWN CHARACTERISTICS AT $T_J=CONSTANT$ (PULSED)



Forward Characteristics

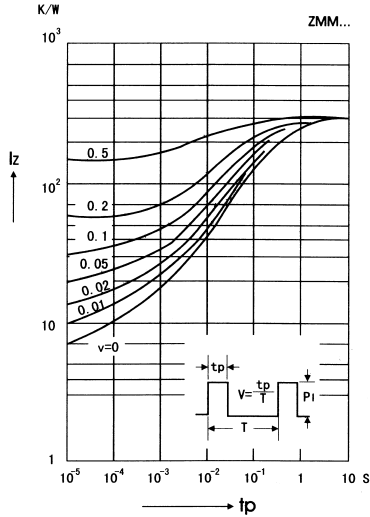


Admissible power dissipation versus ambient temperature

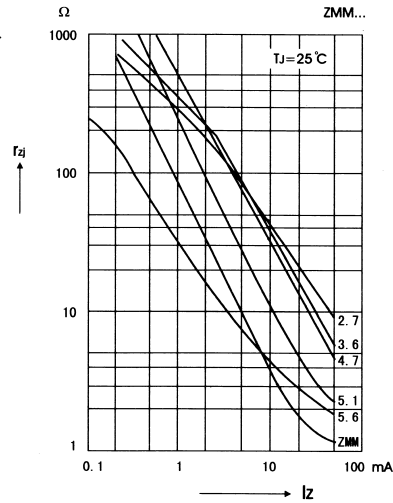


ZMM1...ZMM200 SILICON PLANER ZENER DIODES

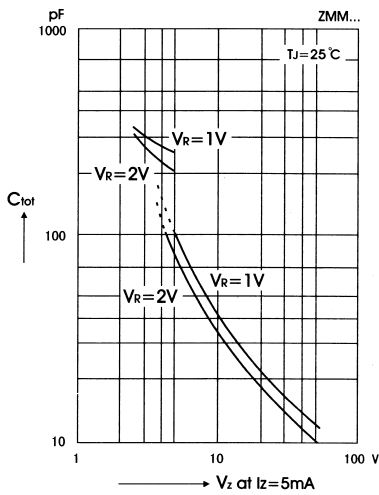
Pulse thermal resistance versus pulse duration



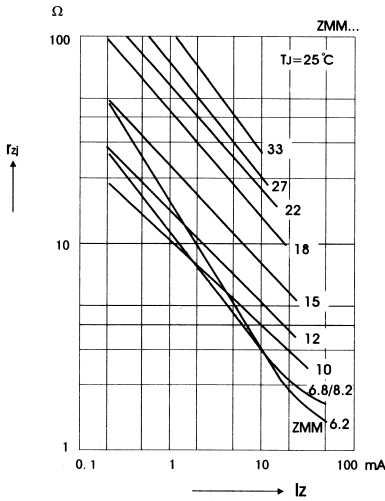
Dynamic resistance versus Zener current



Capacitance versus Zener voltage

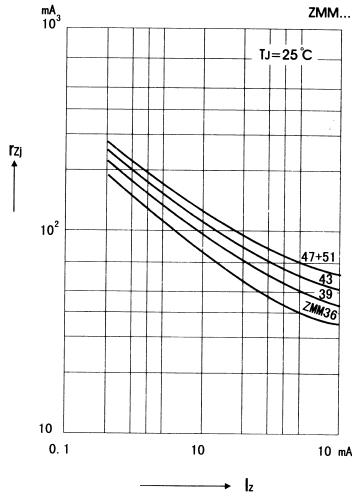


Dynamic resistance versus Zener current

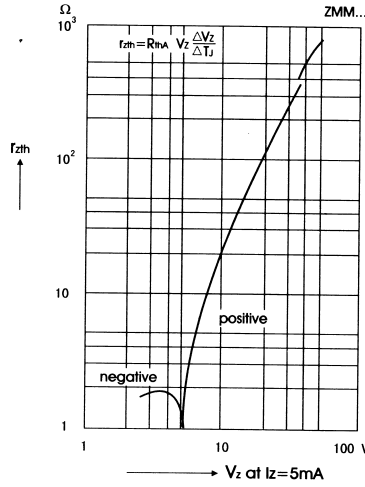


ZMM1...ZMM200 SILICON PLANER ZENER DIODES

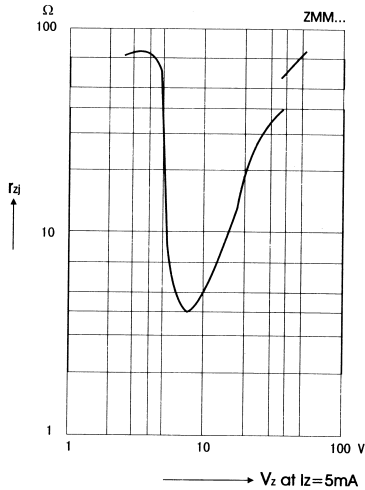
Dynamic resistance versus Zener current



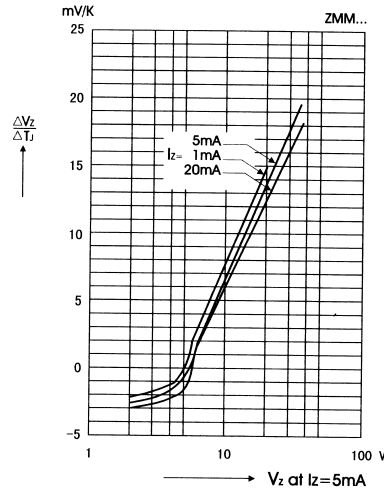
Thermal differential resistance versus Zener voltage



Dynamic resistance versus Zener voltage

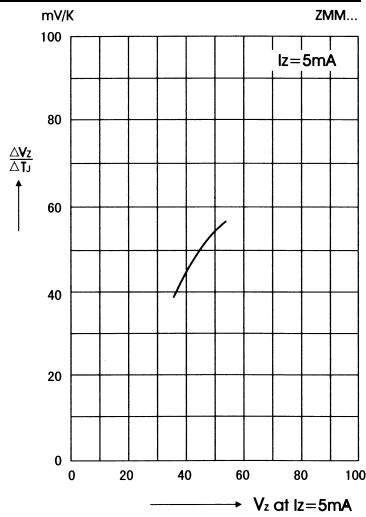


Temperature dependence of Zener voltage versus voltage

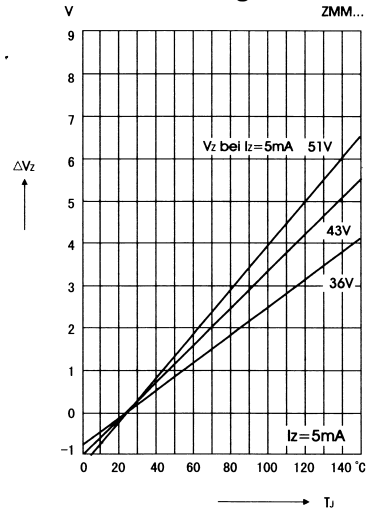


ZMM1...ZMM200 SILICON PLANER ZENER DIODES

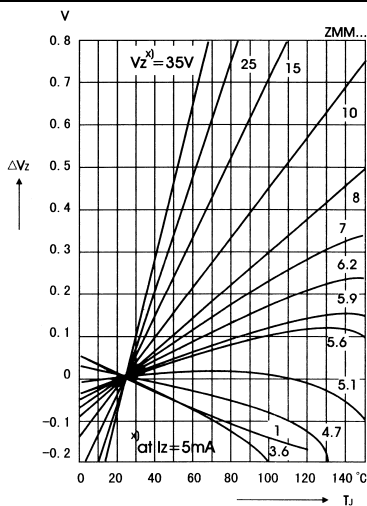
Temperature dependence of Zener voltage versus voltage



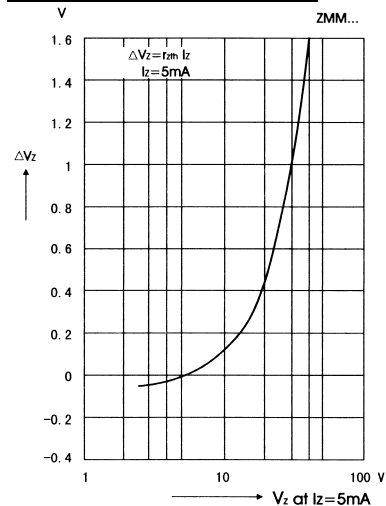
Thermal differential resistance versus Zener voltage



Dynamic resistance versus Zener voltage



Temperature dependence of Zener voltage versus voltage



ZMM1...ZMM200 SILICON PLANER ZENER DIODES

**Temperature dependence of
Zener voltage versus voltage**

